

# Growth of Tin Oxide Thin Film by Aluminum and Fluorine Doping Using Spin Coating Sol-Gel Techniques

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# Growth of Tin Oxide Thin Film by Aluminum and Fluorine Doping Using Spin Coating Sol-Gel Techniques

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**Abstract:** The growth of tin oxide thin film by Aluminum doping and Fluorine has been carried out with the sol-gel spin coating technique. The growth aims to determine the quality of the thin layer formed based on variations in doping aluminum and fluorine. The basic ingredients used were SnCl<sub>2</sub>·2H<sub>2</sub>O, while the doping materials used were Al (Aluminium) and F (Fluorine) with variations in dopant concentrations (0, 5, 10, 15, 20 and 25)%. The growth of a thin layer using measured glass (10x10x 3) mm as a substrate. The growth of thin films includes substrate preparation, sol-gel making, thin film making, and heating processes. The growth of thin layer was dripped on a glass substrate with sol-gel spin coating technique at 1 M sol concentration and treated with maturation for 24 hours. The next step is making a thin layer using a spin coater at a speed of 2000 rpm for 3 minutes. After that, the substrate is heated in an oven at 100°C for 60 minutes. The results showed that the transparency level of the tin oxide layer increases with increasing amounts of doping Aluminum and fluorine.

**Key words:** Aluminum, Fluorine, Sol-gel, Spin Coating, Thin Film, Tin Oxide.

## Introduction

The tin oxide (SnO<sub>2</sub>) is a semiconductor material that has high optical transparency and low resistivity (Doyan et al, 2017). In addition, tin oxide has an energy band gap ranging from 3.6 eV (Schell et al, 2017). Because of its uniqueness, tin oxide is widely applied to capacitors, transistors, diodes, and sensors (Doyan et al, 2018). In addition, tin oxide is very sensitive to gases so that it is widely applied as a sensor gas (Rebholz, 2015).

The advantages of Tin oxide can be modified as needed by providing additional elements (dopants) (Ikraman et al, 2017). Tin oxide is usually doped with indium (Ma et al, 2018), fluorine (Banyan et al, 2014) and aluminum (Gahtar et al, 2014). Tin oxide thin films doped with Aluminum and Fluorine are known to affect the properties of Tin Oxide itself, including stabilizing Tin oxide particles and changing

the energy band gap. In addition, the exposure with Aluminum and Fluorine is known to increase optical transmittance and electrical conductivity, change the structure, and improve response, selectivity, and stability in sensor gases. The addition of Aluminum doping and Fluorine has been carried out by several previous researchers such as Onkundi et al (2018), Doyan et al (2018), Lin et al (2017), Bakr et al (2016) and stated that the growth of Tin oxide layers with doping Aluminum and Fluorine can reduce the Tin oxide energy band gap. But it is not yet known how the effect of the combination of these two dopants on the characteristics of the Tin oxide layer itself. Because of this, further investigation is needed on the effect of these two dopants on the characteristics of the Tin oxide layer. The method of preparation and growth of Tin oxide layers both pure and with doping additions have been carried out by several previous researchers such as DC

sputtering (Mawar<sup>5</sup>i et al, 2006), chemical bath deposition (Maddu et al, 2009), <sup>5</sup> coating (Carvalho et al, 2012), RF sputtering (Xu, et al. 2016), and sol-gel spin coating (Doyan et al, 2018). Of the three techniques, the sol-gel spin coating technique has the advantage that the resulting thin layer is homogeneous because the solution dripped on the substrate is rotated at a certain speed and the influence of the centrifugal force away from the center of rotation (Imawanti et al, 2017).

## Method

The basic material used in this study was 23.697 grams of Tin (II) chloride dihydrate ( $\text{SnCl}_2 \cdot 2\text{H}_2\text{O}$  with a molar mass of 225.63 g/mol, purity of 98%, Merck). The solvent uses 20 ml ethanol ( $\text{C}_2\text{H}_5\text{OH}$ ) with a molar mass of 46.07 gram /mol, purity of 98%, Merck) at room temperature. Materials for doping were used 0.999 grams of Ammonium Fluoride ( $\text{NH}_4\text{F}$ ) with a molar mass of 37 g/mol and 0.444 grams of Aluminum Chloride ( $\text{AlCl}_3$ ) with a molar mass of 133.34 g/mol (98% purity, Merck). The substrate used is glass with size (10x10x3) mm. Other supporting materials are alcohol, distilled water, and detergent which are used to clean the substrate. Thin layer growth includes substrate preparation, sol-gel making, thin film making, and heating process.

The sol-gel maker uses Ammonium Fluoride ( $\text{NH}_4\text{F}$ ) and Aluminum Chloride ( $\text{AlCl}_3$ ) with doping variations (0, 5, 10, 15, 20 and 25)% dissolved in 20 ml ethanol. Then the solution is homogenized using stirring magnetic at room temperature. Sol solution is divided into six parts, namely tin (II) chloride dihydrate with variations in doping Ammonium Fluoride ( $\text{NH}_4\text{F}$ ) and Aluminum Chloride ( $\text{AlCl}_3$ ) of (0, 5, 10, 15, 20 and 25)%. After that, the sol solution was left to stand for 2 days. The next step is making a thin layer using a spin coater at a speed of 2000 rpm for 180 seconds. After that, the substrate is heated in an oven at 100 °C for 60 minutes.

## Result and Discussion

<sup>1</sup> Tin oxide thin films with aluminum doping and fluorine are grown using the sol-gel spin coating method. The basic material used was  $\text{SnCl}_2 \cdot 2\text{H}_2\text{O}$ , while the doping material used was  $\text{AlCl}_3$  and  $\text{NH}_4\text{F}$  with variations in dopant concentration (0, 5, 10, 15 and 20)%. The substrate used is glass with size (10x10x3) mm. The thin layer growth includes substrate preparation, sol-gel making, thin film making, and heating process. Substrate preparation is done by washing the glass substrate with detergent and

drying it using an oven. The purpose of this preparation is to remove dirt and oil from the glass. The next process is making sol-gel with a variety of Aluminum and Fluorine doping: 0, 5, 10, 15, 20 and 25%, then the solution is homogenized using magnetic stirred. The solution is left for two days at room temperature. The amount of mass each from  $\text{SnCl}_2 \cdot 2\text{H}_2\text{O}$ ,  $\text{AlCl}_3$ , and  $\text{NH}_4\text{F}$  is shown in table 1.

Table 1: Doping Percentage and Mass Amount

Material Percentage (%)	$\text{SnCl}_2 \cdot 2\text{H}_2\text{O}$ (g)	$\text{AlCl}_3$ (g)	$\text{NH}_4\text{F}$ (g)
100:0:0	4.5138	0.00	0.00
95:5:0	4.2880	0.0667	0.0185
90:10	4.0624	0.1334	0.0370
85:15	3.8367	0.1999	0.0556
80:20	3.6110	0.2667	0.0741
75:25	3.3853	0.3333	0.0926

The mass of table 1 is obtained from equations 1, 2 and 3 below.

$$(100 - n)\% = \frac{(m_t \text{SnCl}_2 \cdot 2\text{H}_2\text{O}) \times \frac{1}{M_r \text{SnCl}_2 \cdot 2\text{H}_2\text{O}}}{(m_t \text{NH}_4\text{F}) \times \frac{1}{M_r \text{NH}_4\text{F}}} \quad (1)$$

$$(n)\% = \frac{(m_t \text{AlCl}_3) \times \frac{1}{M_r \text{AlCl}_3}}{(m_t \text{SnCl}_2 \cdot 2\text{H}_2\text{O}) \times \frac{1}{M_r \text{SnCl}_2 \cdot 2\text{H}_2\text{O}}} \quad (2)$$

$$(n)\% = \frac{(m_t \text{NH}_4\text{F}) \times \frac{1}{M_r \text{NH}_4\text{F}}}{(m_t \text{SnCl}_2 \cdot 2\text{H}_2\text{O}) \times \frac{1}{M_r \text{SnCl}_2 \cdot 2\text{H}_2\text{O}}} \quad (3)$$

Figure 1 show that the level of transparency of soles produced is higher as the amount of doping Aluminum and fluorine increases. This causes the reaction of  $\text{SnCl}_2$  with ethanol to be reduced due to the addition of Aluminum and fluorine dopants (Ikraman et al, 2017).

The next step is making a thin layer with doping variations using a spin coater at a speed of 2000 rpm for 180 seconds. After that, a thin layer is heated in the oven at 100 °C for 60 minutes. Figure 2 shows a thin layer of tin oxide with variations in aluminum and fluorine doping.

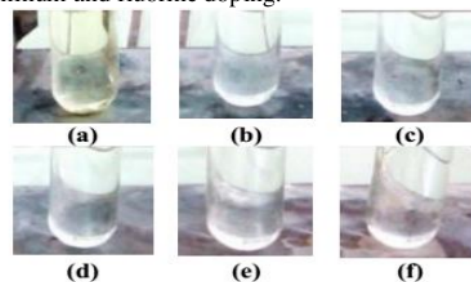
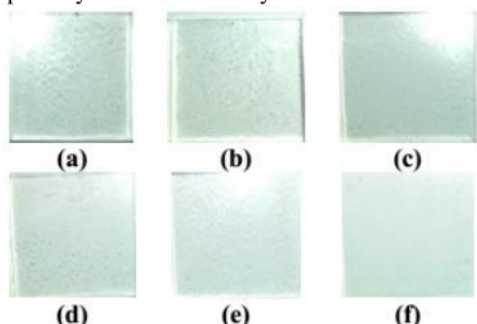


Figure 1. Sol  $\text{SnO}_2$  for variations in doping Aluminum and Fluorine (a) 100: 0%, (b) 95: 5%, (c) 90: 10%, (d) 85: 15%, (e) 80: 20%, (f) 75: 25%

The thin layer formed shows that the addition of Aluminum and Fluorine dopants results in changes in transparency. The greater the concentration of doping aluminum and fluorine, the greater the level of transparency of the formed layer.



**Figure 2** Tin oxide thin layer with variations in doping Aluminum and Fluorine 100: 0%, (b) 95: 5%, (c) 90: 10%, (d) 85: 15%, (e) 80: 20%, (f) 75: 25%.

## Conclusion

The growth of Tin oxide thin layer by doping Aluminum and Fluorine using the sol-gel spin coating technique produced in this study has good transparency along with the increasing concentration of doping given. The higher the concentration of aluminum and fluorine doping, the higher the transparency of the layer.

## References

- Bakr, N.A., Salman, S.A. dan Ali, M.N. (2016). Effect of Fluorine Doping on Structural and Optical Properties of SnO<sub>2</sub> Thin Films Prepared by Chemical Spray Pyrolysis Method. *Advances in Materials*, 5(4): 23-30.
- Benyamin, Z.Y., Kelly, P.J., West, G. dan Boardman, J. (2014). Electrical and Optical Properties of Fluorine-Doped Tin Oxide Thin Films Prepared by Magnetron Sputtering. *Coating*, 4: 732-746.
- Carvalho, D. H. Q., Schiavona, M. A., Raposo, M. T., Paivaa, R., Alvesa, J. L. A., Paniagob, dan Roberto, M. (2012). Synthesis and characterization of SnO<sub>2</sub> thin films prepared by dip-coating method. *Physics Procedia*, 28: 22 – 27.
- Doyan, A., Susilawati, Ikraman, N., and Taufik, M. (2018). Characterization of SnO<sub>2</sub> Film with Al-Zn Doping Using Sol-Gel Dip Coating Techniques. *Journal of Physics*, 1011: 1-6.
- Doyan, A., Susilawati and Imawanti, Y.D. (2017). Synthesis and Characterization of SnO<sub>2</sub> thin layer with a doping Aluminum is deposited on Quartz Substrates. *American Institute of Physics*, 1801: 1-7.
- Doyan, A., Susilawati, Imawanti, Y.D. Gunawan, E.R. and Taufik, M. (2017). Characterization Thin Film Nano Particle Of Aluminum Tin Oxide (AlTO) as Touch Screen. *Journal of Physics*, 1097: 1-9.
- Doyan, A., Susilawati, Fitri, S.A. and Ahzan, S. (2017). Cristal Structure and Characterization of Thin Layer Zinc Oxide. *Materials Science and Engineering*, 196: 1-6.
- Doyan, A., Humaini. (2017). Optical Properties of ZnO Thin Film. *Jurnal Pendidikan Fisika dan Teknologi*, 3(1): 34-39.
- Gahtar A., A. Rahal, B. Benhaoua, S. Benramache. (2014). A Comparative Study on Structural and Optical Properties of ZnO and Al-doped ZnO Thin Films Obtained by Ultrasonic Spray Method Using Different Solvents. Elsevier. *Optik*, 125, 3674–3678.
- Ikraman, N., Doyan, A. dan Susilawati. (2017). Growth of SnO<sub>2</sub> Films with Doping Al-Zn Using the Solgel Dip Coating Technique. *Jurnal Pendidikan Fisika dan Teknologi*, 3(2): 228-231.
- Imawanti, Y.D., Doyan, A. dan Gunawan, E.R. (2017). Thin Film Synthesis of SnO<sub>2</sub> and SnO<sub>2</sub>: Al Using Sol-Gel Spin Coating Technique on Glass Substrates and Quartz. *Jurnal Penelitian Pendidikan IPA*, 3(1): 1-9.
- Lin O.S., Thu, Z., Zaw O. dan Kaung, P. (2017). Optical and Electrical Properties of Antimony and Fluorine Doped Tin Oxide Thin Films. *Universal Journal of Physics and Application*, 11(3): 91-96.
- Ma, Qian. Zheng, He-Mei. Shao, Yan. Zhu, Bao. Liu, Wen-Jun. Ding, Shi-Jin. Zhang, David Wei. (2018). Atomic-Layer-Deposition of Indium Oxide Nano-films for Thin-Film Transistors. *Journal Nanoscale Research Letters*, 13:4.
- Maddu, A., Hasiholan, R. T., Kurniati, M., 2009. Growth of Nanocrystalline SnO<sub>2</sub> Films with Chemical Bath Deposition (CBD) Method, *J. Nano sains dan Teknologi*. Special edition, 96-99.
- Mawarani, L. J. (2006). Characterization of SnO<sub>2</sub> DC Sputtering Thin Layer as CO Gas Sensor Elements, *J. Sains Materi Indonesia*. 8, 35-39
- Onkundi, P. N., Munji, K. M., Bem, D. B., and Muthoka, B. (2018). Effect of Deposition Parameters on Optical and Electrical Properties of SnO<sub>2</sub>: Al Thin Films Prepared by Spray Pyrolysis Technique for Optoelectronic

- Devices. *International Journal of Thin Films Science and Technology*, 1: 25-33.
- Rebholz, J., Dee, C., Weimar, U., Barsan, N. (2015). A self-doping surface effect and its influence on the sensor performance of undoped SnO<sub>2</sub> based gas sensors. *Procedia Engineering 120*: 83 – 87.
- Schell, J., Lupascu, D.C., Carbonari, A.W., Mansano, R.D., Dang, T.T. dan Vianden, R. (2017). Implantation of cobalt in SnO<sub>2</sub> thin films studied by TDPAC. *American Institute of Physics Advances*, 7: 1-7.
- Xu, B. Ren, X. G. Gu, G. R. Lan, L. L. Wu, B.J. (2016). Structural and Optical Properties of Zn-doped SnO<sub>2</sub> Films Prepared by DC and RF-Magnetron Co-Sputtering. *Superlattices and Microstructures*.



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